Dual General Purpose Transistor

The MBT3906DW1T1G device is a spin-off of our popular SOT-23/SOT-323 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-363 six-leaded surface mount package. By putting two discrete devices in one package, this device is ideal for low-power surface mount applications where board space is at a premium.

Features

- h_{FE}, 100-300
- Low $V_{CE(sat)}$, $\leq 0.4 \text{ V}$
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Available in 8 mm, 7-inch/3,000 Unit Tape and Reel
- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V _{CEO}	-40	Vdc
Collector - Base Voltage	V _{CBO}	-40	Vdc
Emitter – Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current - Continuous	I _C	-200 mAd	
Electrostatic Discharge	ESD	HBM Class 2 MM Class B	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Package Dissipation (Note 1) T _A = 25°C	P _D	150	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Device mounted on FR4 glass epoxy printed circuit board using the minimum recommended footprint.

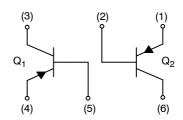


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SOT-363/SC-88 CASE 419B STYLE 1



MARKING DIAGRAM



A2 = Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MBT3906DW1T1G	SOT-363 (Pb-Free)	3,000 / Tape & Reel
SMBT3906DW1T1G	SOT-363 (Pb-Free)	3,000 / Tape & Reel

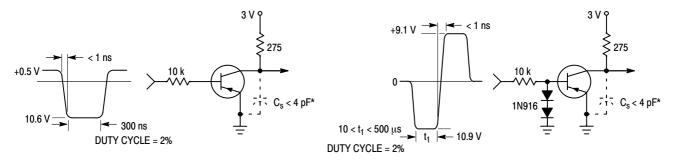
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

	Characteristic	Symbol	Min	Max	Unit
OFF CHARACT	ERISTICS				
Collector – Emitte	r Breakdown Voltage (Note 2)	V _{(BR)CEO}	-40	_	Vdc
Collector - Base I	Breakdown Voltage	V _{(BR)CBO}	-40	-	Vdc
Emitter – Base Br	eakdown Voltage	V _{(BR)EBO}	-5.0	-	Vdc
Base Cutoff Curr	ent	I _{BL}	-	-50	nAdc
Collector Cutoff C	Current	I _{CEX}	-	-50	nAdc
ON CHARACTE	ERISTICS (Note 2)			•	•
$(I_C = -1.0 \text{ mAd})$ $(I_C = -10 \text{ mAd})$ $(I_C = -50 \text{ mAd})$	Ic, $V_{CE} = -1.0 \text{ Vdc}$) Ic, $V_{CE} = -1.0 \text{ Vdc}$) Ic, $V_{CE} = -1.0 \text{ Vdc}$) Ic, $V_{CE} = -1.0 \text{ Vdc}$) Idc, $V_{CE} = -1.0 \text{ Vdc}$)	h _{FE}	60 80 100 60 30	- 300 - -	-
$(I_C = -10 \text{ mAdd})$	or Saturation Voltage c, $I_B = -1.0$ mAdc) c, $I_B = -5.0$ mAdc)	V _{CE(sat)}	- -	-0.25 -0.4	Vdc
	aturation Voltage c, $I_B = -1.0$ mAdc) c, $I_B = -5.0$ mAdc)	V _{BE(sat)}	-0.65 -	-0.85 -0.95	Vdc
SMALL-SIGNA	L CHARACTERISTICS				
Current-Gain -	Bandwidth Product	f _T	250	=	MHz
Output Capacitar	nce	C _{obo}	-	pF	
Input Capacitanc	е	C _{ibo}	-	10.0	pF
Input Impedance (V _{CE} = -10 Vd	c, I _C = -1.0 mAdc, f = 1.0 kHz)	h _{ie}	2.0	12	kΩ
Voltage Feedbac (V _{CE} = -10 Vd	k Ratio c, I _C = -1.0 mAdc, f = 1.0 kHz)	h _{re}	0.1	10	X 10 ⁻⁴
Small – Signal Cu (V _{CE} = -10 Vd	rrent Gain c, I _C = -1.0 mAdc, f = 1.0 kHz)	h _{fe}	100	400	-
Output Admittand (V _{CE} = -10 Vd	ce c, I _C = -1.0 mAdc, f = 1.0 kHz)	h _{oe}	3.0	60	μmhos
Noise Figure (V _{CE} = -5.0 Vo	dc, $I_C = -100 \mu\text{Adc}$, $R_S = 1.0 \text{k}\Omega$, $f = 1.0 \text{kHz}$)	NF		4.0	dB
SWITCHING CH	HARACTERISTICS				
Delay Time	$(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc})$	t _d	-	35	
Rise Time	ime $(I_C = -10 \text{ mAdc}, I_{B1} = -1.0 \text{ mAdc})$ t_r			35	ns
Storage Time	(V _{CC} = -3.0 Vdc, I _C = -10 mAdc)	t _s	_	225	
Fall Time	$(I_{B1} = I_{B2} = -1.0 \text{ mAdc})$	t _f	_	75	ns

Fall Time $(I_{B1} = I_{B2} = -1.0 \text{ mAdc})$ 2. Pulse Test: Pulse Width $\leq 300 \mu s$; Duty Cycle $\leq 2.0\%$.



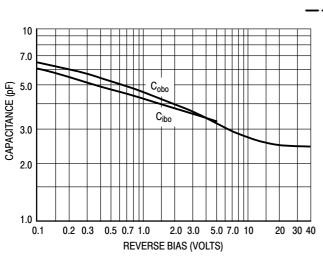
* Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit

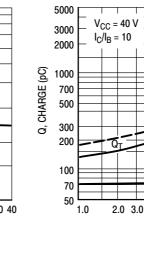
Figure 2. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS

T_J = 25°C
 T_J = 125°C







I_C, COLLECTOR CURRENT (mA)

Figure 4. Charge Data

50 70 100

200

5.0 7.0 10

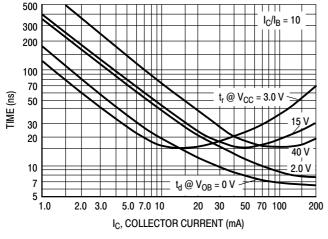


Figure 5. Turn - On Time

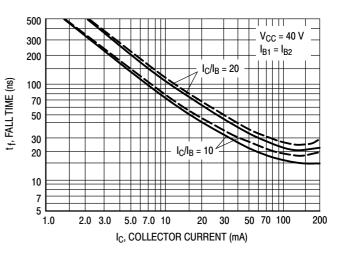
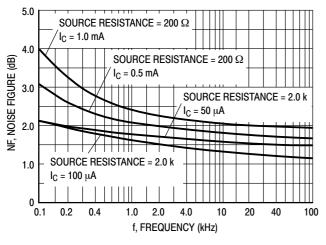


Figure 6. Fall Time

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$



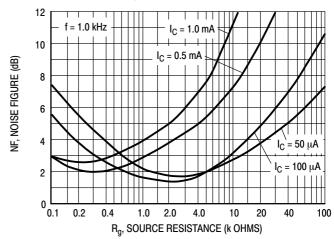
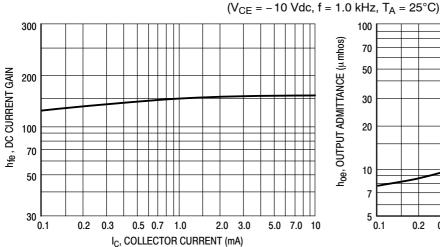


Figure 7.

Figure 8.

h PARAMETERS



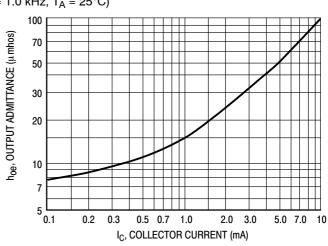


Figure 9. Current Gain

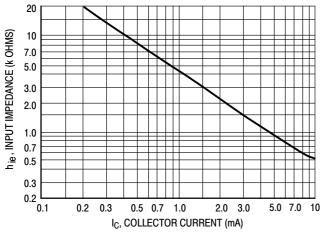


Figure 11. Input Impedance

Figure 10. Output Admittance

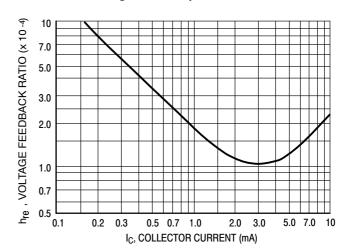


Figure 12. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

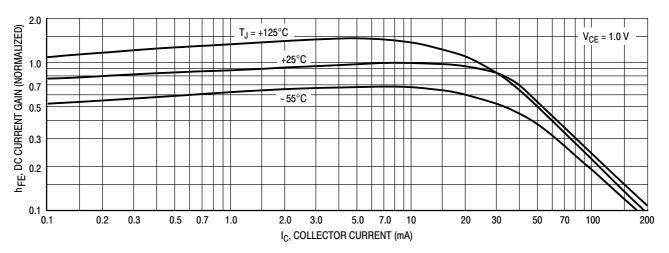


Figure 13. DC Current Gain

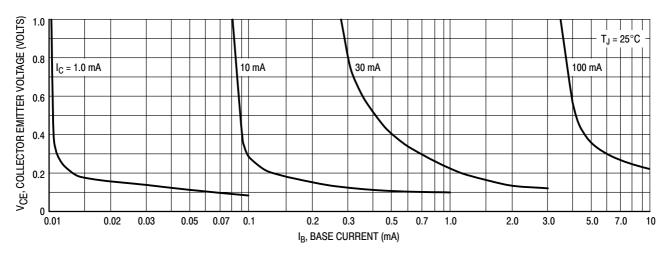


Figure 14. Collector Saturation Region

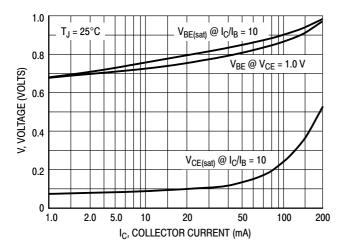


Figure 15. "ON" Voltages

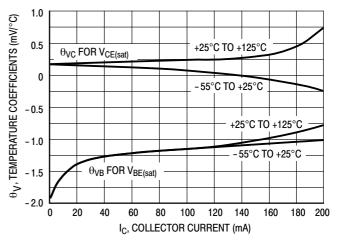
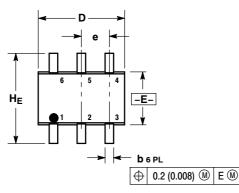
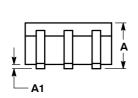


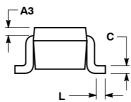
Figure 16. Temperature Coefficients

PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02 **ISSUE W**







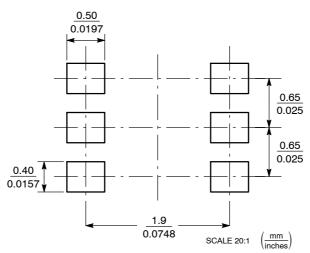
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH
- 3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
А3	0.20 REF			0.008 REF		
b	0.10	0.21	0.30	0.004	0.008	0.012
С	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
Е	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65 BSC			0.026 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	2.00	2.10	2.20	0.078	0.082	0.086

- STYLE 1: PIN 1. EMITTER 2
 - 2. BASE 2 3. COLLECTOR 1
 - EMITTER 1
 - 5. BASE 1
 - **COLLECTOR 2**

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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